



SWS150

RELIABILITY DATA

DWG No. CA732-57-01			
QA APPD	APPD	CHK	DWG
	 23.May.03	Jackson 21-May-03	Joe 21-May'03

I N D E X

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※ The above data is typical value. As all units have nearly the same characteristics, the data to be considered as ability value.

1. CALCULATED VALUES OF MTBF

MODEL : SWS150-5

(1) Calculating method

Calculated based on part count reliability projection of JEITA (RCR-9102).

Individual failure rates λ_G is given to each part and MTBF is calculated by the count of each part.

<Formula> :

$$MTBF = \frac{1}{\lambda_{equip}} = \frac{1}{\sum_{i=1}^n N_i (\lambda_G \pi_Q)_i} \times 10^6 \text{ (Hours)}$$

λ_{equip} : Total Equipment Failure Rate (Failure/10⁶ Hours)

λ_G : Generic Failure Rate for The ith Generic Part (Failure/10⁶ Hours)

N_i : Quantity of ith Generic Part

n : Number of Different Generic Part Categories

π_Q : Generic Quality Factor for The ith Generic Part ($\pi_Q = 1$)

(2) MTBF Values

G_F : (Ground , Fixed)

MTBF ≒ 420,582(Hours)

2. COMPONENT DERATING

MODEL : SWS150-5

(1) Calculating Method

(a) Measuring Conditions

Input : 100/200VAC • Ambient temperature : 45°C
 Output : 5V 20A(100%) • Mounting method : Standard Mounting

(b) Semiconductors

Compared with maximum junction temperature and actual one which is calculated based on case temperature, power dissipation and thermal impedance.

(c) IC, Resistors, Capacitors, etc.

Ambient temperature, operating condition, power dissipation and so on are within derating criteria.

(d) Calculating Method of Thermal Impedance

$$\theta_{j-c} = \frac{T_{j(\max)} - T_c}{P_{c(\max)}} \quad \theta_{j-a} = \frac{T_{j(\max)} - T_a}{P_{c(\max)}} \quad \theta_{j-l} = \frac{T_{j(\max)} - T_l}{P_{c(\max)}}$$

T_c : Case Temperature at Start Point of Derating ; 25°C in General

T_a : Ambient Temperature at Start Point of Derating ; 25°C in General

T_l : Lead Temperature at Start Point of Derating ; 25°C in General

$P_{c(\max)}$
($P_{ch(\max)}$) : Maximum Collector(channel) Dissipation

$T_{j(\max)}$
($T_{ch(\max)}$) : Maximum Junction(channel) Temperature

θ_{j-c}
(θ_{ch-c}) : Thermal Impedance between Junction(channel) and Case

θ_{j-a} : Thermal Impedance between Junction and Air

θ_{j-l} : Thermal Impedance between Junction and Lead

(2) Component Derating List

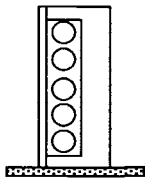
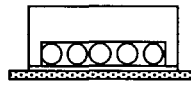
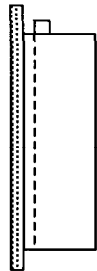
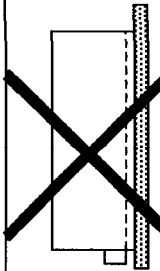

Location No.	Vin = 100VAC	Load = 100%	Ta = 25°C (Convection cooling)
Q1 2SK2837 TOSHIBA	Tchmax = 150 °C, Pch = 6.68W, Tch = Tc + ((θ ch-c) × Pch) = 85.0 °C D.F. = 56.7%	θ ch-c = 0.83 °C/W, Δ Tc = 54.5 °C,	Pch(max) = 150 W, Tc = 79.5 °C
Q2 2SK2611 TOSHIBA	Tchmax = 150 °C, Pch = 8.30W, Tch = Tc + ((θ ch-c) × Pch) = 96.7 °C D.F. = 64.5%	θ ch-c = 0.83 °C/W, Δ Tc = 64.8 °C,	Pch(max) = 150 W, Tc = 89.8 °C
Q102 2SK2177-4061 SHINDENGEN	Tjmax = 150 °C, Pch = 0.03W, Tch = Tc + ((θ ch-c) × Pch) = 82.3 °C D.F. = 54.9%	θ ch-c = 12.50 °C/W, Δ Tc = 56.9 °C,	Pch(max) = 10 W, Tc = 81.9 °C
D1 D3SB60 SHINDENGEN	Tjmax = 150 °C, Pd = 3.5 W, Tj = Tc + ((θ j-c) × Pd) = 124.7 °C D.F. = 83.1%	θ j-c = 5.5 °C/W, Δ Tc = 80.4 °C,	Tc = 105.4 °C
D2 YG911S3R FUJI-ELE	Tjmax = 150 °C, Pd = 1.56 W, Tj = Tc + ((θ j-c) × Pd) = 103.4 °C D.F. = 68.9%	θ j-c = 3.50 °C/W, Δ Tc = 72.9 °C,	Tc = 97.9 °C
D51 S30SC4M SHINDENGEN	Tjmax = 150 °C, Pd = 8.25 W, Tj = Tc + ((θ j-c) × Pd) = 109.0 °C D.F. = 72.7%	θ j-c = 1.0 °C/W, Δ Tc = 70.0 °C,	Tc = 95 °C
A101 FA5502M-TE1 FUJI-ELE	Tjmax = 150 °C, Pd = 0.09W, Tj = Tc + ((θ j-c) × Pd) = 106.3 °C D.F. = 70.9%	θ j-c = 50.00 °C/W, Δ Tc = 76.8 °C,	Tc = 101.8 °C
A102 M51995AFP-600C MITSUBISHI	Tjmax = 150 °C, Pd = 0.35 W, Tj = Ta + ((θ j-c) × Pd) = 123.9 °C D.F. = 82.6%	θ j-c = 40 °C/W, Δ Tc = 84.9 °C,	Tc = 109.9 °C
A201 UPC1093T-E1 NEC	Tjmax = 150 °C, Pd = 0.03W, Tj = Ta + ((θ j-a) × Pd) = 94.2 °C D.F. = 62.8%	θ j-a = 315 °C/W, Δ Ta = 59.7 °C,	Ta = 84.7 °C
PC1 TLP721F (D4-GR,M) (LED) TOSHIBA	Tjmax = 150 °C, If = 0 mA, ALLOWABLE If(max) = 29mA (at Ta = 84.2 °C) D.F. = 0 %	Δ If / °C = -0.7mA / °C, Δ Ta = 59.2 °C,	If(max) = 60mA, Ta = 84.2 °C
PC1 TLP721F (D4-GR,M) (Transistor) TOSHIBA	Tjmax = 150 °C, Pd = 0 W, Tj = Ta + ((θ j-a) × Pd) = 84.2 °C D.F. = 56.1 %	θ j-a = 667 °C/W, Δ Ta = 59.2 °C,	Pc(max) = 150 mW, Ta = 84.2 °C
PC2 TLP721F (D4-GR,M) (LED) TOSHIBA	Tjmax = 150 °C, If = 1.2 mA, ALLOWABLE If(max) = 29mA (at Ta = 84.4 °C) D.F. = 4.1 %	Δ If / °C = -0.7mA / °C, Δ Ta = 59.4 °C,	If(max) = 60mA, Ta = 84.4 °C
PC2 TLP721F (D4-GR,M) (Transistor) TOSHIBA	Tjmax = 150 °C, Pd = 25 mW, Tj = Ta + ((θ j-a) × Pd) = 101.1 °C D.F. = 67.4 %	θ j-a = 667 °C/W, Δ Ta = 59.4 °C,	Pc(max) = 150 mW, Ta = 84.4 °C

Location No.	Vin = 200VAC	Load = 100%	Ta = 25°C (Convection cooling)
Q1 2SK2837 TOSHIBA	Tchmax = 150 °C, Pch = 2.27W, Tch = Tc + ((θ ch-c) × Pch) = 72.9 °C D.F. = 48.5%	θ ch-c = 0.83 °C/W, Δ Tc = 45.8 °C,	Pch(max) = 150 W, Tc = 70.8 °C
Q2 2S2611 TOSHIBA	Tchmax = 150 °C, Pch = 8.30W, Tch = Tc + ((θ ch-c) × Pch) = 91.7 °C D.F. = 61.1%	θ ch-c = 0.83 °C/W, Δ Tc = 61.2 °C,	Pch(max) = 150 W, Tc = 86.2 °C
Q102 2SK2177-4061 SHINDENGEN	Tjmax = 150 °C, Pch = 0.03W, Tch = Tc + ((θ ch-c) × Pch) = 71.4 °C D.F. = 47.6%	θ ch-c = 12.50 °C/W, Δ Tc = 46.0 °C,	Pch(max) = 10 W, Tc = 71 °C
D1 D3SB60 SHINDENGEN	Tjmax = 150 °C, Pd = 1.7 W, Tj = Tc + ((θ j-c) × Pd) = 86.3°C D.F. = 57.5%	θ j-c = 5.5 °C/W, Δ Tc = 51.9 °C,	Tc = 76.9 °C
D2 YG911S3R FUJI-ELE	Tjmax = 150 °C, Pd = 0.96 W, Tj = Tc + ((θ j-c) × Pd) = 92.2 °C D.F. = 61.5%	θ j-c = 3.50 °C/W, Δ Tc = 63.8 °C,	Tc = 88.8 °C
D51 S30SC4M SHINDENGEN	Tjmax = 150 °C, Pd = 8.25 W, Tj = Tc + ((θ j-c) × Pd) = 100.8 °C D.F. = 67.2%	θ j-c = 1.0 °C/W, Δ Tc = 67.5 °C,	Tc = 92.5 °C
A101 FA5502M-TE1 FUJI-ELE	Tjmax = 150 °C, Pd = 0.09W, Tj = Ta + ((θ j-c) × Pd) = 100.5 °C D.F. = 67.0%	θ j-c = 50.00 °C/W, Δ Tc = 71.0 °C,	Tc = 96 °C
A102 M51995AFP-600C MITSUBISHI	Tjmax = 150 °C, Pd = 0.35 W, Tj = Ta + ((θ j-c) × Pd) = 120.7 °C D.F. = 80.5%	θ j-c = 40 °C/W, Δ Tc = 81.7 °C,	Tc = 106.7 °C
A201 UPC1093T-E1 NEC	Tjmax = 150 °C, Pd = 0.03W, Tj = Ta + ((θ j-a) × Pd) = 93.6 °C D.F. = 62.4%	θ j-a = 315 °C/W, Δ Ta = 59.1 °C,	Ta = 84.1 °C
PC1 TLP721F (D4-GR,M) (LED) TOSHIBA	Tjmax = 150 °C, If = 0 mA, ALLOWABLE If(max) = 34mA (at Ta = 77.1°C) D.F. = 0 %	Δ If/°C = -0.7mA /°C, Δ Ta = 52.1 °C,	If(max) = 60mA, Ta = 77.1 °C
PC1 TLP721F (D4-GR,M) (Transistor) TOSHIBA	Tjmax = 150 °C, Pd = 0 W, Tj = Ta + ((θ j-a) × Pd) = 77.1 °C D.F. = 51.4%	θ j-a = 667°C/W, Δ Ta = 52.1 °C,	Pc(max) = 150 mW, Ta = 77.1 °C
PC2 TLP721F (D4-GR,M) (LED) TOSHIBA	Tjmax = 150 °C, If = 1.2 mA, ALLOWABLE If(max) = 34mA (at Ta = 77.7°C) D.F. = 3.5 %	Δ If/°C = -0.7mA /°C, Δ Ta = 52.7 °C,	If(max) = 60mA, Ta = 77.7 °C
PC2 TLP721F (D4-GR,M) (Transistor) TOSHIBA	Tjmax = 150 °C, Pd = 25 mW, Tj = Ta + ((θ j-a) × Pd) = 94.4°C D.F. = 62.9%	θ j-a = 667°C/W, Δ Ta = 52.7 °C,	Pc(max) = 150 mW, Ta = 77.7 °C

3. MAIN COMPONENTS TEMPERATURE RISE ΔT LIST

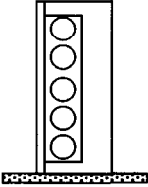
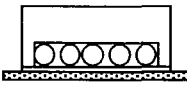
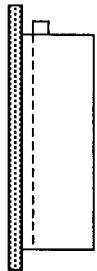
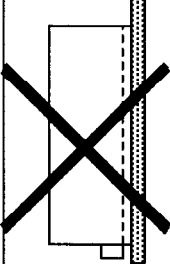

MODEL : SWS150-5

Measuring Conditions (Convection cooling)

Mounting Method (Standard Mounting Method:(A))	(A)	(B)	(C)	DON'T USE	DON'T USE
					
Input Voltage (VAC)	100			NOT RECOMMENDED	
Output Voltage (VDC)	5				
Output Current (A)	30				

		ΔT Temperature rise (°C)		
Output Derating (%)		100 (Ta =25°C)	100 (Ta =15°C)	100 (Ta =15°C)
Location No.	Parts Name	Mounting A	Mounting B	Mounting C
L1	BALUN COIL	48.2	63.1	73.1
L51	CHOKE COIL	88.6	96.0	94.3
T1	TRANS PULSE	86.4	99.0	85.6
A101	CHIP IC	76.8	81.3	74.8
A102	CHIP IC	84.9	83.7	76.3
D1	BRIDGE DIODE	80.4	94.8	94.6
Q1	MOS-FET	54.5	57.8	55.9
Q2	MOS-FET	64.8	67.2	65.6
D51	OUTPUT DIODE	70.0	65.4	72.8
C5	E. CAP.	56.6	73.0	75.2
C6	E. CAP.	40.0	56.6	39.2
C7	E. CAP.	60.9	64.9	56.3
C51	E. CAP.	70.7	71.5	89.3

Measuring Conditions (Convection cooling)

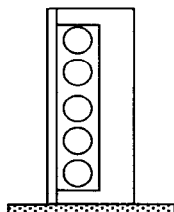
Mounting Method (Standard Mounting Method:(A))	(A)	(B)	(C)	DON'T USE	DON'T USE
					
Input Voltage (VAC)	200			NOT RECOMMENDED	
Output Voltage (VDC)	5				
Output Current (A)	30				

Output Derating (%)		ΔT Temperature rise ($^{\circ}C$)		
		100 ($T_a = 25^{\circ}C$)	100 ($T_a = 15^{\circ}C$)	100 ($T_a = 15^{\circ}C$)
Location No.	Parts Name	Mounting A	Mounting B	Mounting C
L1	BALUN COIL	31.0	42.9	51.3
L51	CHOKE COIL	86.5	94.1	91.8
T1	TRANS PULSE	81.6	94.3	82.8
A101	CHIP IC	71.0	80.5	74.8
A102	CHIP IC	81.7	85.9	78.9
D1	BRIDGE DIODE	51.9	64.5	66.6
Q1	MOS-FET	45.8	47.9	49.1
Q2	MOS-FET	61.2	62.7	63.7
D51	OUTPUT DIODE	67.5	64.1	71.3
C5	E. CAP.	41.1	55.8	58.4
C6	E. CAP.	32.4	45.2	34.2
C7	E. CAP.	57.2	62.2	57.1
C51	E. CAP.	69.1	67.7	89.1

4. ELECTROLYTIC CAPACITOR LIFETIME

MODEL: SWS150-5

Mounting A

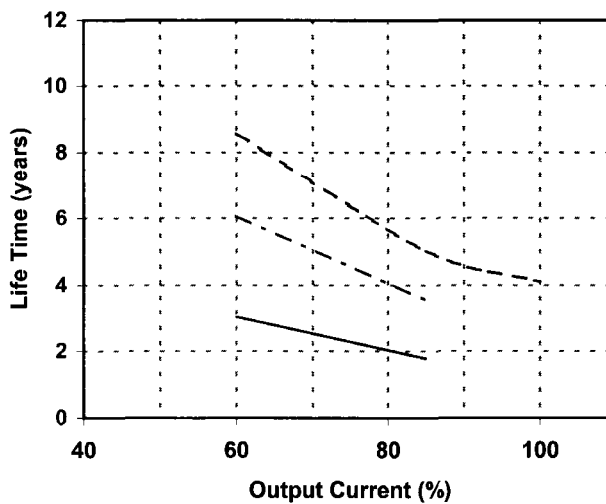


Vin = 100VAC

※ Convection cooling .

Load (%)	Life Time (years)			
	Ta = 25°C	Ta = 30°C	Ta = 40°C	Ta = 50°C
60	8.6	6.1	3.0	1.5
85	5.0	3.6	1.8	---
100	4.1	---	---	---

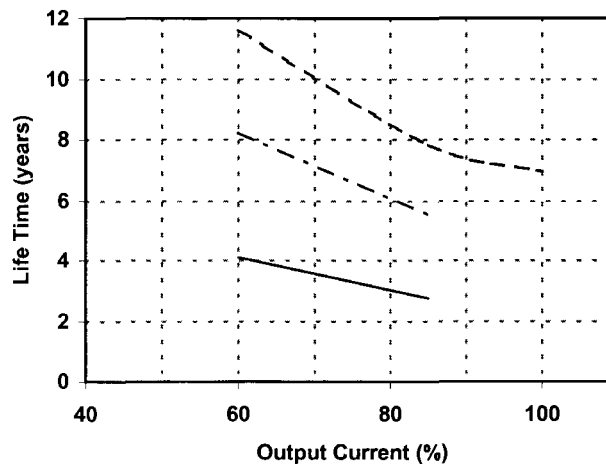
Ta = 25°C - - - - -
 Ta = 30°C - · - · - ·
 Ta = 40°C ————



Vin = 200VAC

※ Convection cooling .

Load (%)	Life Time (years)			
	Ta = 25°C	Ta = 30°C	Ta = 40°C	Ta = 50°C
60	11.6	8.2	4.1	2.1
85	7.8	5.5	2.8	---
100	7.0	---	---	---



Formula:

1. For 105°C Elect. capacitor

$$L = L_o * 2^{(105-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

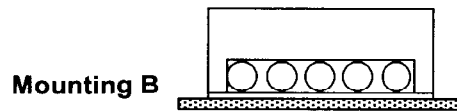
2. For 85°C Elect. capacitor

$$L = L_o * 2^{(85-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

Where:

- L ——— Elec. Capacitor computed life (8 hours per day , 365 days operation)
- L_o ——— Guarantee life for Elec. capacitor
- T_a ——— Ambient temperature
- ΔT ——— Temperature rise of Elec. capacitor

MODEL: SWS150-5

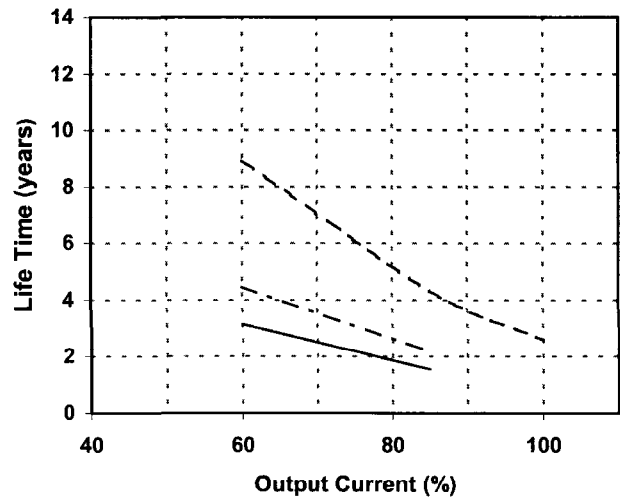


Ta = 15°C - - - - -
 Ta = 25°C - - - - -
 Ta = 30°C - - - - -

Vin = 100VAC

※ Convection cooling .

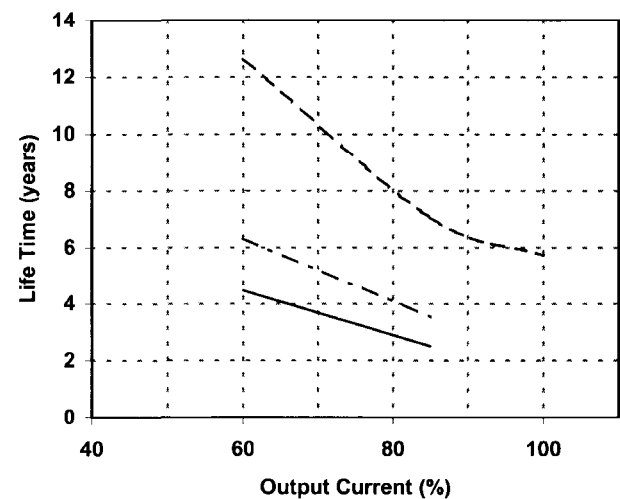
Load (%)	Life Time (years)			
	Ta = 15°C	Ta = 25°C	Ta = 30°C	Ta = 45°C
60	8.9	4.5	3.2	1.1
85	4.3	2.2	1.5	---
100	2.6	---	---	---



Vin = 200VAC

※ Convection cooling .

Load (%)	Life Time (years)			
	Ta = 15°C	Ta = 25°C	Ta = 30°C	Ta = 45°C
60	12.6	6.3	4.5	1.6
85	7.1	3.5	2.5	---
100	5.7	---	---	---



Formula:

1. For 105°C Elect. capacitor

$$L = L_o * 2^{(105-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

2. For 85°C Elect. capacitor

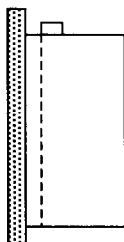
$$L = L_o * 2^{(85-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

Where:

- L — Elec. Capacitor computed life (8 hours per day , 365 days operation)
- L_o — Guarantee life for Elec. capacitor
- T_a — Ambient temperature
- ΔT — Temperature rise of Elec. capacitor

MODEL: SWS150-5

Mounting C

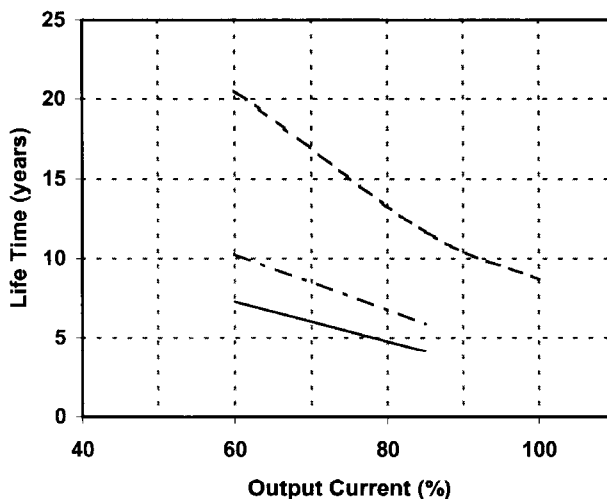


Vin = 100VAC

※ Convection cooling .

Load (%)	Life Time (years)			
	Ta = 15°C	Ta = 25°C	Ta = 30°C	Ta = 45°C
60	20.5	10.3	7.3	2.6
85	11.7	5.9	4.1	---
100	8.7	---	---	---

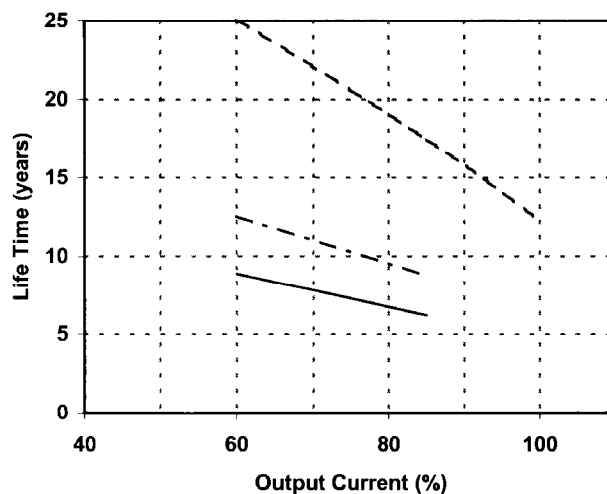
Ta = 15°C -----
 Ta = 25°C - - - - -
 Ta = 30°C _____



Vin = 200VAC

※ Convection cooling .

Load (%)	Life Time (years)			
	Ta = 15°C	Ta = 25°C	Ta = 30°C	Ta = 45°C
60	25.1	12.5	8.9	3.1
85	17.5	8.7	6.2	---
100	12.3	---	---	---



Formula:

1. For 105°C Elect. capacitor

$$L = L_o * 2^{(105-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

2. For 85°C Elect. capacitor

$$L = L_o * 2^{(85-\Delta T-T_a)/10} / (8 * 365) \text{ (years)}$$

Where:

- L — Elec. Capacitor computed life (8 hours per day , 365 days operation)
- L_o — Guarantee life for Elec. capacitor
- T_a — Ambient temperature
- ΔT — Temperature rise of Elec. capacitor

5. VIBRATION TEST

MODEL : SWS150-12

(1) Vibration Test Class

Frequency Variable Endurance Test

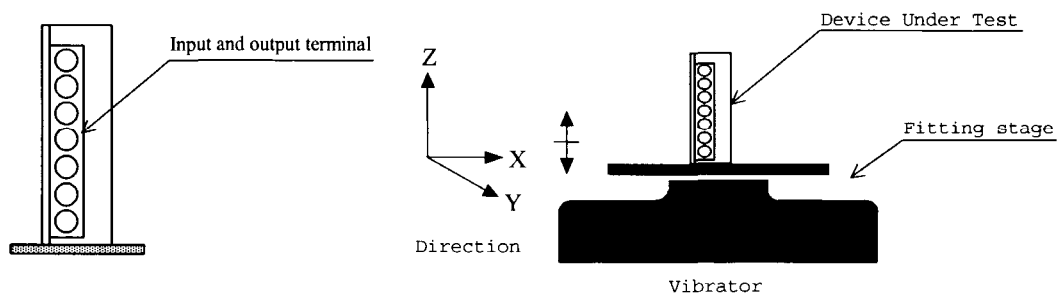
(2) Equipment Used

- Controller : DP550 (DP CORP. USA)
- Vibrator : V870 (LDS CORP. UK)

(3) Test Conditions

- Sweep frequency 10 ~ 55Hz
- Sweep time 1.0 min.
- Acceleration Constant 19.6m/s² (2G)
- Direction X, Y, Z.
- Test time 1 hour each

(4) Test Method



(5) Test Results

OK

Vin : 200VAC

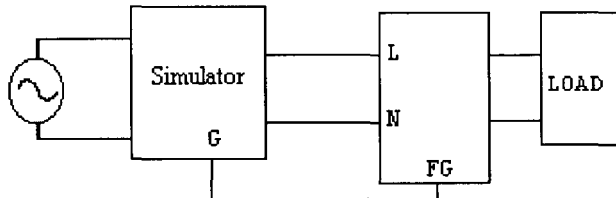
Iout : 100%

Check item	Output Voltage (V)	Ripple Voltage (mVp-p)	D.U.T.State
Before Test	12.001	60	_____
After Test	X	12.003	O.K.
	Y	12.003	O.K.
	Z	12.004	O.K.

6. NOISE SIMULATE TEST

MODEL : SWS150-5 , 24

(1) Test Circuit And Equipment



Simulator : INS-400L Noise Laboratory Co.,LTD

(2) Test Conditions

- | | | | |
|-----------------------|-----------------|------------------|--------------------|
| • Input Voltage | : 100, 200VAC | • Noise Level | : 0V~2kV |
| • Output Voltage | : Rated | • Phase Shift | : 0° ~ 360° |
| • Output Current | : 0%, 100% | • Polarity | : + , - |
| • Ambient Temperature | : 25°C | • Mode | : Normal
Common |
| • Pulse Width | : 50ns ~ 1000ns | • Trigger Select | : Line |

(3) Acceptable Conditions

1. Not to be broken.
2. Not to be shut down output.
3. No other out of orders.

(4) Test Result

OK